NSN 5961-01-259-5551

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.310 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 gate to source voltage and 500.0 drain to source voltage

Current Rating Per Characteristic:

32.00 amperes off-state current, peak

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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